

KSC4010

Audio Power Amplifier

- High Current Capability : I_C=6A
- High Power Dissipation
- Wide S.O.A
- Complement to KSA3010



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	120	V
V _{CEO}	Collector-Emitter Voltage	120	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	6	Α
I _{CP}	Collector Current (Pulse)	12	Α
P _C	Collector Dissipation (T _C =25°C)	60	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 50 ~ 150	°C

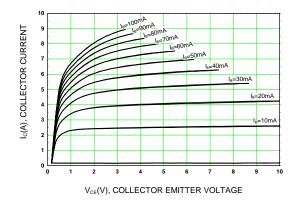
Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	V _{CB} = 120V, I _E = 0	-	-	10	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V$, $I_C = 0$	-	-	10	μΑ
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 5A,, I _B = 0	120	-	-	V
h _{FE}	DC Current Gain	V _{CE} = 5V, I _C = 1A,	55	-	160	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 5A, I _B = 0.5A	-	-	2.5	V
V _{BE} (on)	Base-Emitter ON Voltage	V _{CE} = 5V, I _C = 5A	-	-	1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} = 5V, I _C = 1A	-	30	-	MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz	-	90	-	pF

h_{FE} Classification

Classification	R	0	
h _{FE}	55 ~ 110	80 ~ 160	

Typical Characteristics



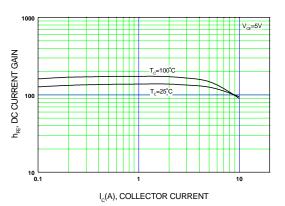
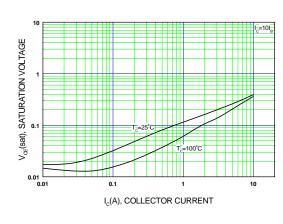


Figure 1. Static Characteristic

Figure 2. DC current Gain



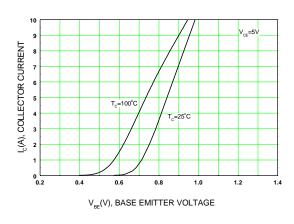
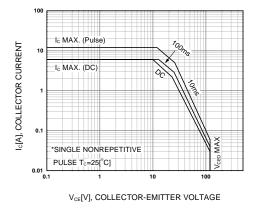


Figure 3. Collector-Emitter Saturation Voltage

Figure 4. Base-Emitter On Voltage



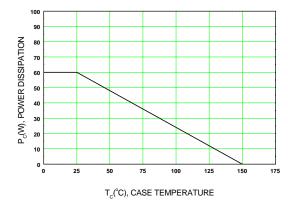


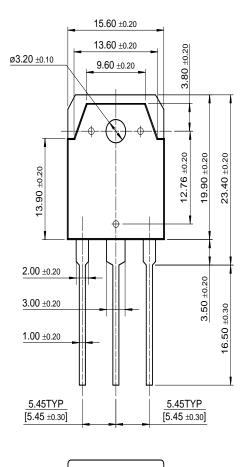
Figure 5. Safe Operating Area

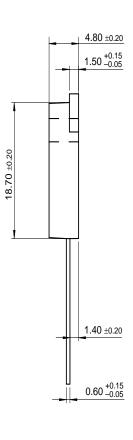
Figure 6. Power Derating

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Package Demensions

TO-3P





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